

Triacs

BT136X series

GENERAL DESCRIPTION

Glass passivated triacs in a full pack plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

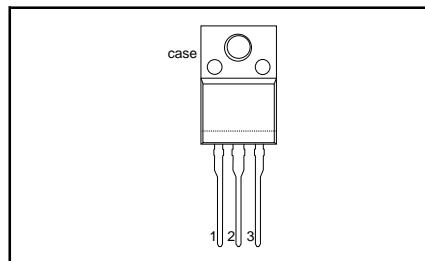
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{DRM}	Repetitive peak off-state voltages	BT136X-500	600	800	V
		BT136X-500F	600F	800F	
		BT136X-500G	600G	800G	
$I_{T(RMS)}$	RMS on-state current	4	4	4	A
I_{TSM}	Non-repetitive peak on-state current	25	25	25	A

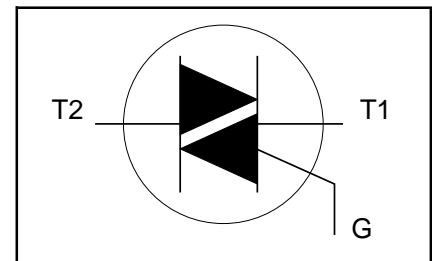
PINNING - SOT186A

PIN	DESCRIPTION
1	main terminal 1
2	main terminal 2
3	gate
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				-500	-600	-800	
V_{DRM}	Repetitive peak off-state voltages		-	500 ¹	600 ¹	800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; $T_{hs} \leq 92^\circ C$	-	4			A
I_{TSM}	Non-repetitive peak on-state current	full sine wave; $T_j = 125^\circ C$ prior to surge; with reapplied $V_{DRM(max)}$	-	25			A
I^2t	I^2t for fusing	$t = 20\ ms$	-	27			A
di_T/dt	Repetitive rate of rise of on-state current after triggering	$t = 16.7\ ms$	-	3.1			A ² s
		$t = 10\ ms$	-	10			A/μs
		$I_{TM} = 6\ A; I_G = 0.2\ A;$	-	50			A/μs
		$di_G/dt = 0.2\ A/\mu s$	-	50			A/μs
		T2+ G+	-	50			A/μs
		T2+ G-	-	10			A/μs
		T2- G-	-	2			A
		T2- G+	-	5			V
I_{GM}	Peak gate current		-	5			W
V_{GM}	Peak gate voltage		-	0.5			W
P_{GM}	Peak gate power		-	150			°C
$P_{G(AV)}$	Average gate power	over any 20 ms period	-	125			°C
T_{stg}	Storage temperature		-40				
T_j	Operating junction temperature		-				

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 A/μs.

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ISOLATION LIMITING VALUE & CHARACTERISTIC $T_{hs} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	$f = 50\text{-}60\text{ Hz}$; sinusoidal waveform; $R.H. \leq 65\%$; clean and dustfree	-		2500	V
C_{isol}	Capacitance from T2 to external heatsink	$f = 1\text{ MHz}$	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Thermal resistance junction to heatsink	full or half cycle with heatsink compound	-	-	5.5	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	without heatsink compound in free air	-	55	7.2	K/W

STATIC CHARACTERISTICS $T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.			UNIT
I_{GT}	Gate trigger current	BT136X- $V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$		F	...G	
		T2+ G+	-	5	35	25	50	mA
		T2+ G-	-	8	35	25	50	mA
		T2- G-	-	11	35	25	50	mA
		T2- G+	-	30	70	70	100	mA
I_L	Latching current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$						
		T2+ G+	-	7	20	20	30	mA
		T2+ G-	-	16	30	30	45	mA
		T2- G-	-	5	20	20	30	mA
		T2- G+	-	7	30	30	45	mA
I_H	Holding current	$V_D = 12\text{ V}$; $I_{GT} = 0.1\text{ A}$	-	5	15	15	30	mA
V_T	On-state voltage	$I_T = 5\text{ A}$	-	1.4	1.70			V
V_{GT}	Gate trigger voltage	$V_D = 12\text{ V}$; $I_T = 0.1\text{ A}$	-	0.7	1.5			V
		$V_D = 400\text{ V}$; $I_T = 0.1\text{ A}$; $T_j = 125\text{ }^{\circ}\text{C}$	0.25	0.4	-			V
I_D	Off-state leakage current	$V_D = V_{DRM(max)}$; $T_j = 125\text{ }^{\circ}\text{C}$	-	0.1	0.5			mA

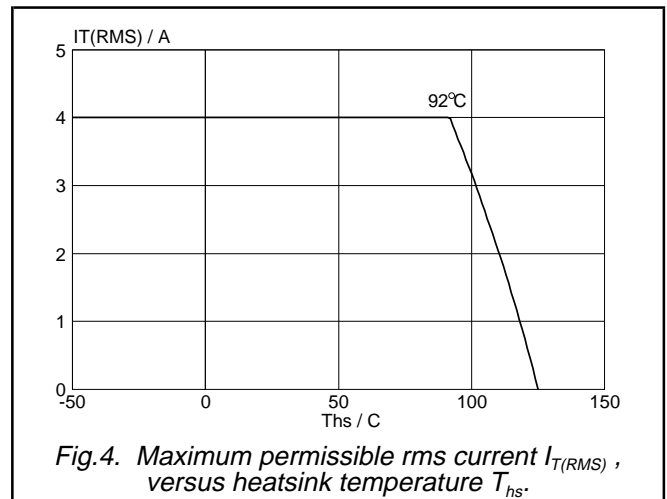
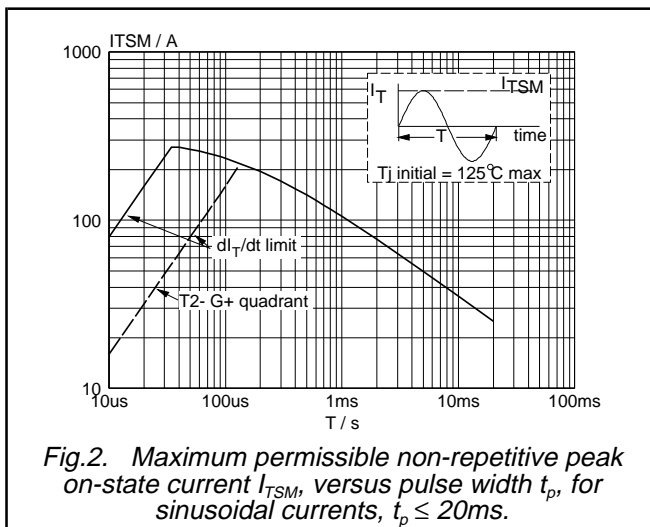
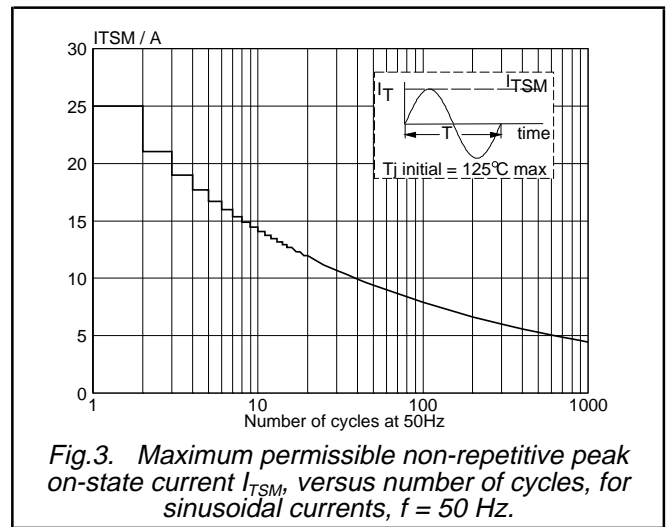
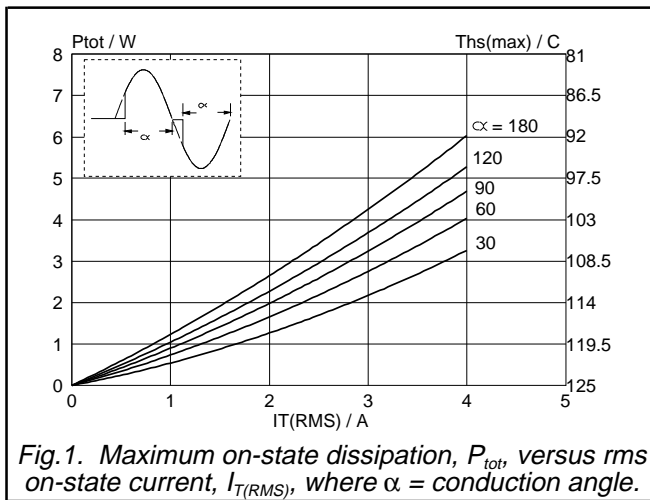
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DYNAMIC CHARACTERISTICS

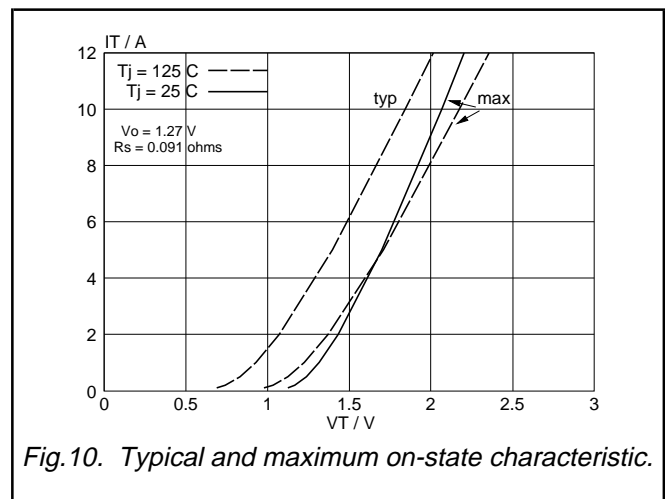
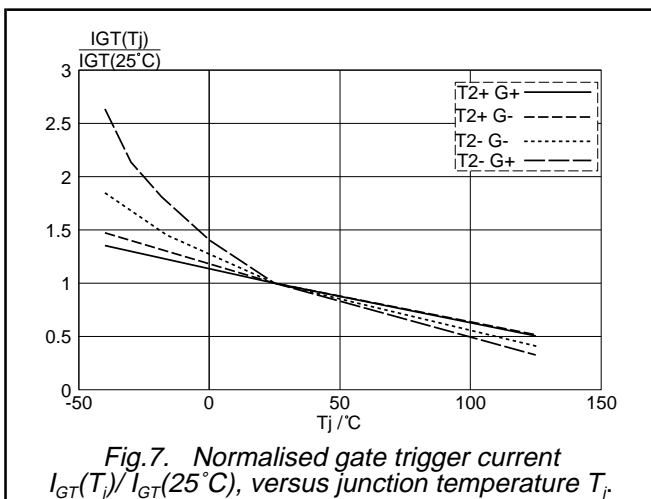
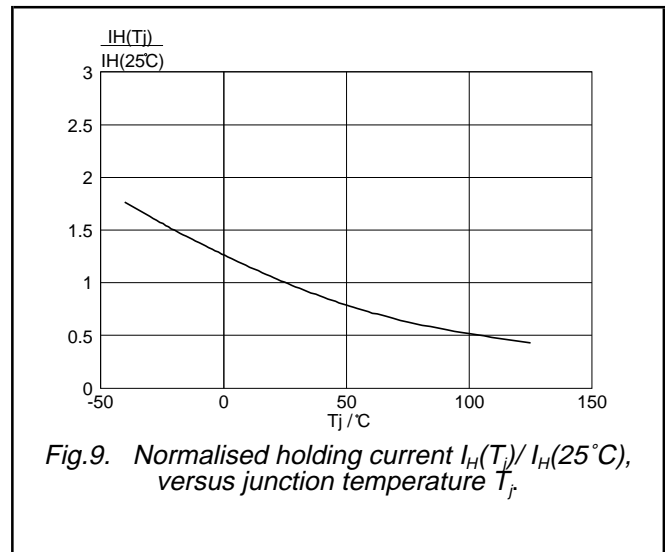
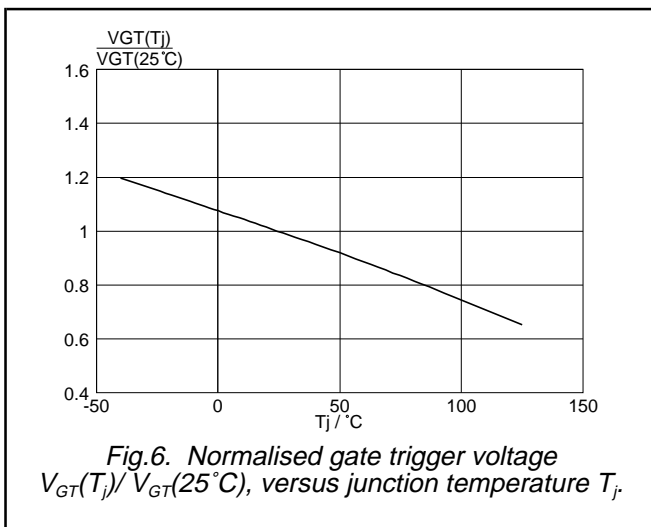
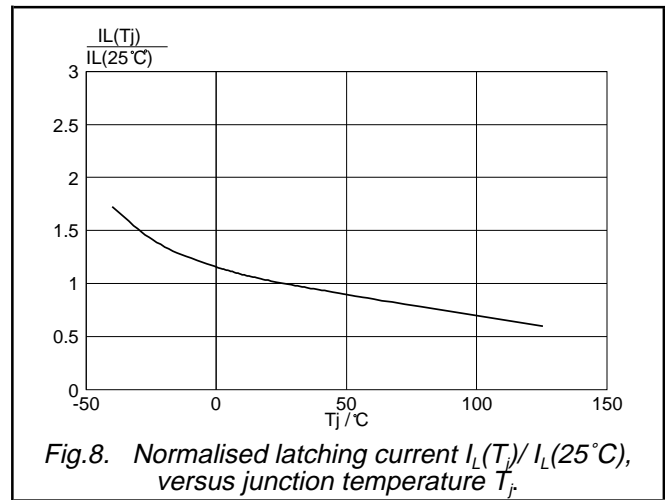
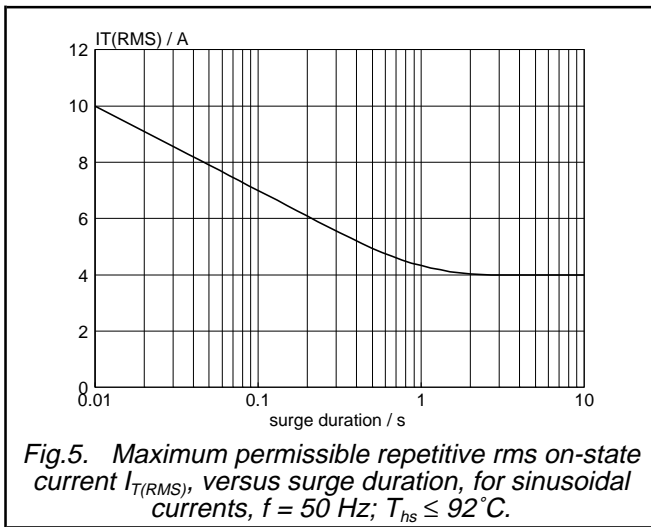
$T_j = 25\text{ }^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.			TYP.	MAX.	UNIT
dV_D/dt	Critical rate of rise of off-state voltage	BT136X- $V_{DM} = 67\% V_{DRM(max)}$; $T_j = 125\text{ }^\circ\text{C}$; exponential waveform; gate open circuit	100	50	200	250	-	V/ μs
dV_{com}/dt	Critical rate of change of commutating voltage	$V_{DM} = 400\text{ V}$; $T_j = 95\text{ }^\circ\text{C}$; $I_{T(RMS)} = 4\text{ A}$; $dl_{com}/dt = 1.8\text{ A/ms}$; gate open circuit	-	-	10	50	-	V/ μs
t_{gt}	Gate controlled turn-on time	$I_{TM} = 6\text{ A}$; $V_D = V_{DRM(max)}$; $I_G = 0.1\text{ A}$; $dl_G/dt = 5\text{ A}/\mu\text{s}$	-	-	-	2	-	μs



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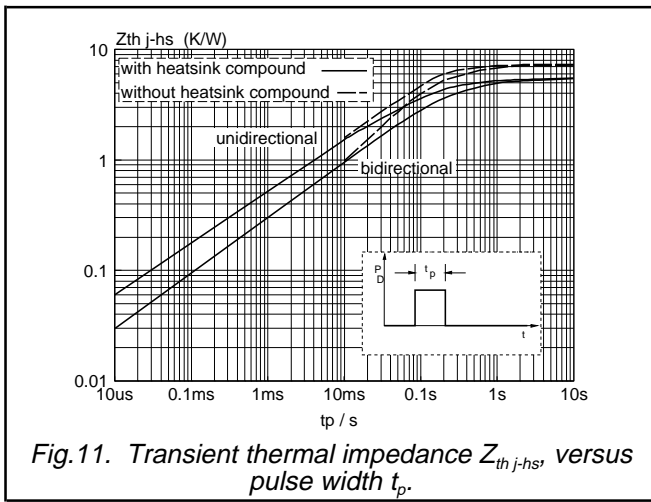


Fig.11. Transient thermal impedance $Z_{th\ j-hs}$ versus pulse width t_p .

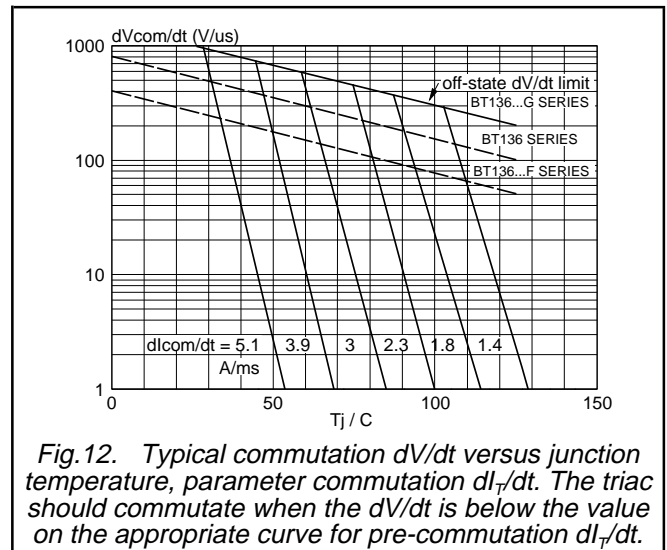


Fig.12. Typical commutation dV/dt versus junction temperature, parameter commutation dI_T/dt . The triac should commute when the dV/dt is below the value on the appropriate curve for pre-commutation dI_T/dt .

MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

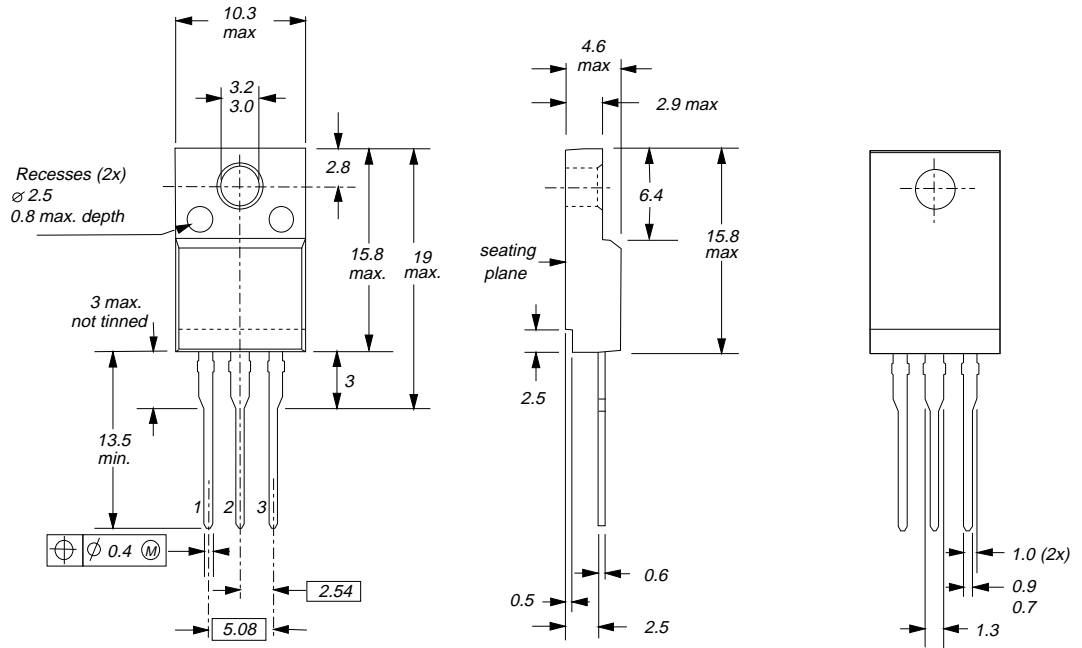


Fig. 13. SOT186A; The seating plane is electrically isolated from all terminals.

Notes

1. Accessories supplied on request: refer to mounting instructions for F-pack envelopes.
2. The improved isolation rating applies only to the SOT186 version A envelope.

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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